TOSHIBA 2SB1020A

TOSHIBA TRANSISTOR SILICON PNP TRIPLE DIFFUSED TYPE (DARLINGTON POWER)

# 2 S B 1 0 2 0 A

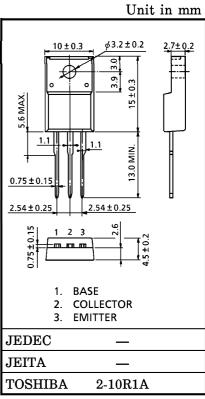
#### HIGH POWER SWITCHING APPLICATIONS

HAMMER DRIVE, PULSE MOTOR DRIVE APPLICATIONS

- High DC Current Gain
  - :  $h_{FE} = 2000$  (Min.) (at  $V_{CE} = -3V$ ,  $I_{C} = -3A$ )
- Low Saturation Voltage
  - :  $V_{CE (sat)} = -1.5V (Max.) (at I_C = -3A)$
- Complementary to 2SD1415A

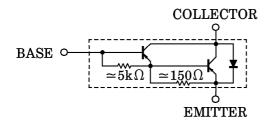
### MAXIMUM RATINGS (Tc = 25°C)

| CHARACTERIS'              | SYMBOL                    | RATING             | UNIT                 |                      |  |
|---------------------------|---------------------------|--------------------|----------------------|----------------------|--|
| Collector-Base Voltage    | $v_{\mathrm{CBO}}$        | -100               | V                    |                      |  |
| Collector-Emitter Voltage |                           | $v_{CEO}$          | -100                 | V                    |  |
| Emitter-Base Voltage      | $V_{ m EBO}$              | -5                 | V                    |                      |  |
| Callastan Cromont         | DC                        | $I_{\mathbf{C}}$   | <b>-</b> 7           | A                    |  |
| Collector Current         | Pulse                     | $I_{CP}$           | -10                  | A                    |  |
| Base Current              | $I_{\mathbf{B}}$          | -0.7               | A                    |                      |  |
| Collector Power           | $Ta = 25^{\circ}C$        | $P_{\mathbf{C}}$   | 2.0                  | w                    |  |
| Dissipation               | $Tc = 25^{\circ}C$        | 10                 | 30                   |                      |  |
| Junction Temperature      | $\mathbf{T}_{\mathbf{j}}$ | 150                | $^{\circ}\mathrm{C}$ |                      |  |
| Storage Temperature Range |                           | $\mathrm{T_{stg}}$ | -55~150              | $^{\circ}\mathrm{C}$ |  |



Weight: 1.7g (Typ.)

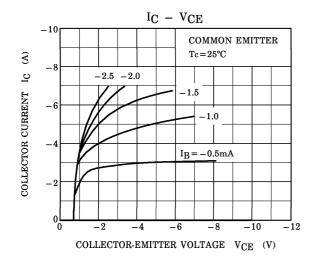
### **EQUIVALENT CIRCUIT**

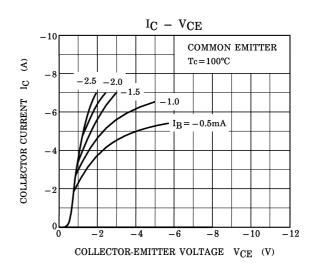


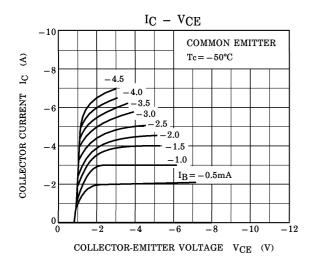
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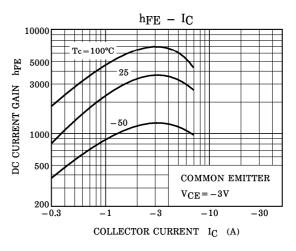
## ELECTRICAL CHARACTERISTICS (Tc = 25°C)

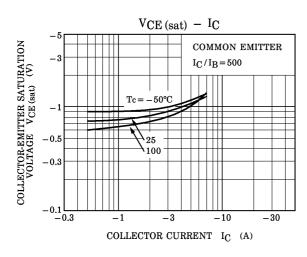
|                                    |               | 1                         | T T T T T T T T T T T T T T T T T T T  |      |       | 1     |         |
|------------------------------------|---------------|---------------------------|--|------|-------|-------|---------|
| CHARACTERISTIC                     |               | SYMBOL                    | TEST CONDITION   | MIN. | TYP.  | MAX.  | UNIT    |
| Collector Cut-off Current          |               | ICBO                      | $V_{CB} = -100V, I_{E} = 0$  | _    | _     | -100  | $\mu$ A |
| Emitter Cut-off Current            |               | I <sub>EBO</sub>          | $V_{EB} = -5V, I_C = 0$  | _    | _     | -4.0  | mA      |
| Collector-Emit<br>Voltage          | ter Breakdown | V (BR) CEO                | $I_{\rm C} = -50  {\rm mA}, \ I_{\rm B} = 0$   | -100 | -     | _     | V       |
| DC Current Gain                    |               | hFE (1)                   | $V_{CE} = -3V, I_{C} = -3A$  | 2000 |       | 15000 |         |
|                                    |               | h <sub>FE</sub> (2)       | $V_{CE} = -3V, I_{C} = -7A$  | 1000 |       |       |         |
| Collector-Emitter Saturation       |               | V <sub>CE</sub> (sat) (1) | $I_{C} = -3A, I_{B} = -6mA$  |      | -0.95 | -1.5  | v       |
| Voltage                            |               | VCE (sat) (2)             | $I_C = -7A$ , $I_B = -14mA$  |      | -1.3  | -2.0  | v       |
| Base-Emitter Saturation<br>Voltage |               |                           | $I_{C} = -3A, I_{B} = -6mA$  |      | -1.55 | -2.5  | V       |
| Switching<br>Time                  | Turn-on Time  | t <sub>on</sub>           | OUTPUT $I_{B_1}$ $I_{B_2}$ $I_{B_2}$ $I_{B_2}$ $I_{B_1}$ $I_{B_1}$ $I_{B_1}$ $I_{B_1}$ $I_{B_2}$ $I_{B_1}$ $I_{B_1}$ $I_{B_2}$ $I_{B_2}$ $I_{B_1}$ $I_{B_2}$ |      | 0.8   |       |         |
|                                    | Storage Time  | $t_{	ext{stg}}$           |  |      | 2.0   |       | $\mu$ s |
|                                    | Fall Time     | tf                        |  | _    | 2.5   |       |         |

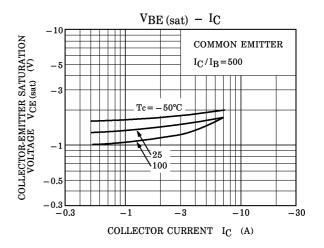


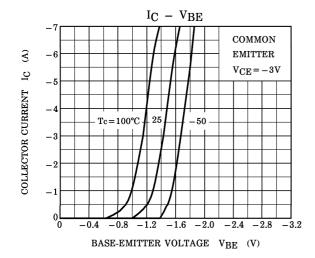


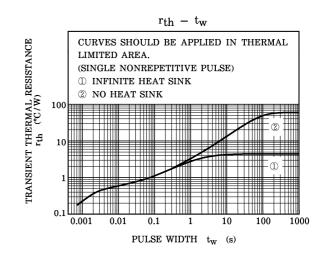


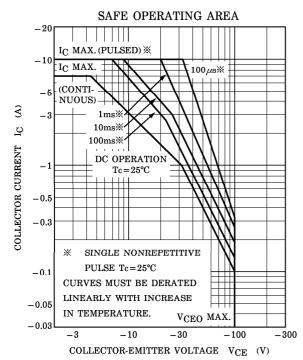












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